ON Semiconductor

Is Now

To learn more about onsemi™, please visit our website at
www.onsemi.com

MC14043B, MC14044B

CMOS MSI

Quad R−S Latches

The MC14043B and MC14044B quad R−S latches are constructed with MOS P−Channel and N−Channel enhancement mode devices in a single monolithic structure. Each latch has an independent Q output and set and reset inputs. The Q outputs are gated through three−state buffers having a common enable input. The outputs are enabled with a logical “1” or high on the enable input; a logical “0” or low disconnects the latch from the Q outputs, resulting in an open circuit at the Q outputs.

Features

- Double Diode Input Protection
- Three−State Outputs with Common Enable
- Outputs Capable of Driving Two Low−power TTL Loads or One Low−Power Schottky TTL Load Over the Rated Temperature Range
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	−0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage Range (DC or Transient)	−0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P_D	Power Dissipation, per Package (Note 1)	500	mW
T_A	Ambient Temperature Range	−55 to +125	°C
T_{stg}	Storage Temperature Range	−65 to +150	°C
T_L	Lead Temperature (8−Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

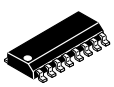
1. Temperature Derating: “D/DW” Packages: –7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in}$ or $V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

ON Semiconductor®

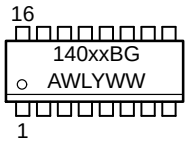
http://onsemi.com



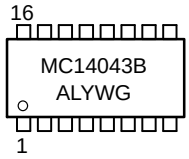
SOIC−16
D SUFFIX
CASE 751B

SOEIAJ−16
F SUFFIX
CASE 966

MARKING DIAGRAMS



SOIC−16



SOEIAJ−16

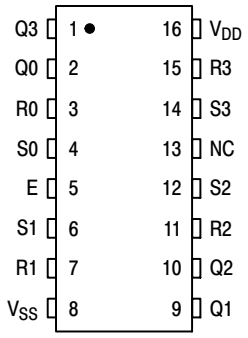
xx	= Specific Device Code
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G	= Pb−Free Indicator

ORDERING INFORMATION

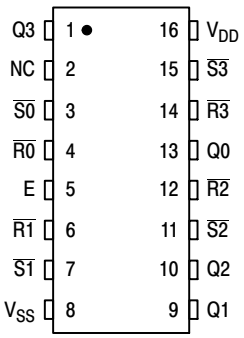
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

PIN ASSIGNMENT

MC14043B

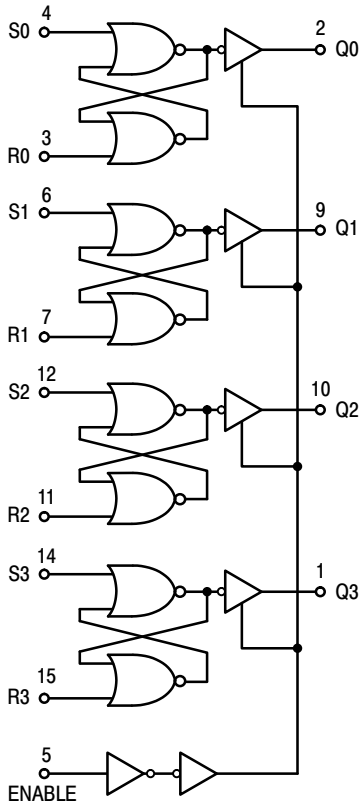


MC14044B



NC = NO CONNECTION

MC14043B



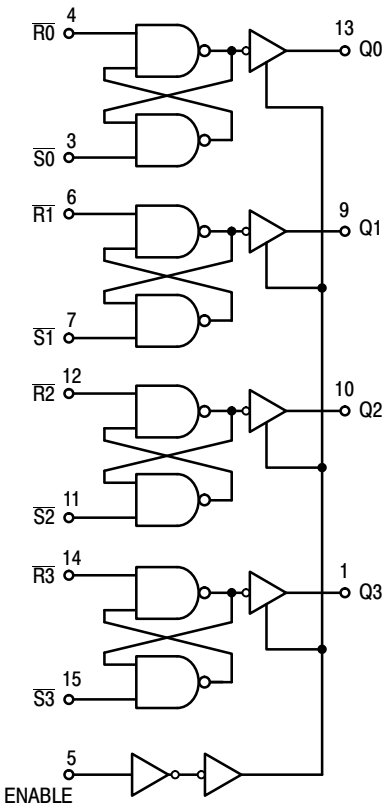
V_{DD} = PIN 16
V_{SS} = PIN 8
NC = PIN 13

TRUTH TABLE

S	R	E	Q
X	X	0	High Impedance
0	0	1	No Change
0	1	1	0
1	0	1	1
1	1	1	1

X = Don't Care

MC14044B



V_{DD} = PIN 16
V_{SS} = PIN 8
NC = PIN 2

TRUTH TABLE

$\overline{S}$	$\overline{R}$	E	Q
X	X	0	High Impedance
0	0	1	0
0	1	1	1
1	0	1	0
1	1	1	No Change

X = Don't Care

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	− 55°C Min	− 55°C Max	25°C Min	25°C Typ (Note 2)	25°C Max	125°C Min	125°C Max	Unit
Output Voltage “0” Level V_{in} = V_{DD} or 0	V_{OL}	5.0 10 15	− − −	0.05 0.05 0.05	− − −	0 0 0	0.05 0.05 0.05	− − −	0.05 0.05 0.05	Vdc
“1” Level V_{in} = 0 or V_{DD}	V_{OH}	5.0 10 15	4.95 9.95 14.95	− − −	4.95 9.95 14.95	5.0 10 15	− − −	4.95 9.95 14.95	− − −	Vdc
Input Voltage “0” Level (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)	V_{IL}	 5.0 10 15	 − − −	 1.5 3.0 4.0	 − − −	 2.25 4.50 6.75	 1.5 3.0 4.0	 − − −	 1.5 3.0 4.0	Vdc
“1” Level (V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)	V_{IH}	 5.0 10 15	 3.5 7.0 11	 − − −	 3.5 7.0 11	 2.75 5.50 8.25	 − − −	 3.5 7.0 11	 − − −	Vdc
Output Drive Current (V_{OH} = 2.5 Vdc) Source (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)	I_{OH}	 5.0 5.0 10 15	 –3.0 –0.64 –1.6 –4.2	 − − − −	 –2.4 –0.51 –1.3 –3.4	 –4.2 –0.88 –2.25 –8.8	 − − − −	 –1.7 –0.36 –0.9 –2.4	 − − − −	mAdc
(V_{OL} = 0.4 Vdc) Sink (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)	I_{OL}	5.0 10 15	0.64 1.6 4.2	− − −	0.51 1.3 3.4	0.88 2.25 8.8	− − −	0.36 0.9 2.4	− − −	mAdc
Input Current	I_{in}	15	−	±0.1	−	±0.00001	±0.1	−	±1.0	μAdc
Input Capacitance (V_{in} = 0)	C_{in}	−	−	−	−	5.0	7.5	−	−	pF
Quiescent Current (Per Package)	I_{DD}	5.0 10 15	− − −	1.0 2.0 4.0	− − −	0.002 0.004 0.006	1.0 2.0 4.0	− − −	30 60 120	μAdc
Total Supply Current (Notes 3 & 4) (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs all buffers switching)	I_T	5.0 10 15	I_T = (0.58 μA/kHz) f + I_{DD} I_T = (1.15 μA/kHz) f + I_{DD} I_T = (1.73 μA/kHz) f + I_{DD}							μAdc
Three−State Output Leakage Current	I_{TL}	15	−	±0.1	−	±0.0001	±0.1	−	±3.0	μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} − V_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

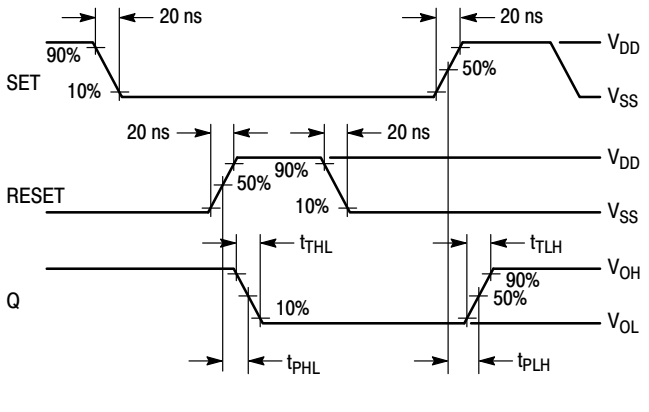
SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise Time	t_{TLH}					ns
t_{TLH} = (1.35 ns/pF) C_L + 32.5 ns		5.0	–	100	200	
t_{TLH} = (0.60 ns/pF) C_L + 20 ns		10	–	50	100	
t_{TLH} = (0.40 ns/pF) C_L + 20 ns		15	–	40	80	
Output Fall Time	t_{THL}					ns
t_{THL} = (1.35 ns/pF) C_L + 32.5 ns		5.0	–	100	200	
t_{THL} = (0.60 ns/pF) C_L + 20 ns		10	–	50	100	
t_{THL} = (0.40 ns/pF) C_L + 20 ns		15	–	40	80	
Propagation Delay Time	t_{PLH}					ns
t_{PLH} = (0.90 ns/pF) C_L + 130 ns		5.0	–	175	350	
t_{PLH} = (0.36 ns/pF) C_L + 57 ns		10	–	75	175	
t_{PLH} = (0.26 ns/pF) C_L + 47 ns		15	–	60	120	
t_{PHL} = (0.90 ns/pF) C_L + 130 ns	t_{PHL}	5.0	–	175	350	ns
t_{PHL} = (0.90 ns/pF) C_L + 57 ns		10	–	75	175	
t_{PHL} = (0.26 ns/pF) C_L + 47 ns		15	–	60	120	
Set, $\overline{\text{Set}}$ Pulse Width	t_W	5.0	200	80	–	ns
		10	100	40	–	
		15	70	30	–	
Reset, $\overline{\text{Reset}}$ Pulse Width	t_W	5.0	200	80	–	ns
		10	100	40	–	
		15	70	30	–	
Three−State Enable/Disable Delay	t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}	5.0	–	150	300	ns
		10	–	80	160	
		15	–	55	110	

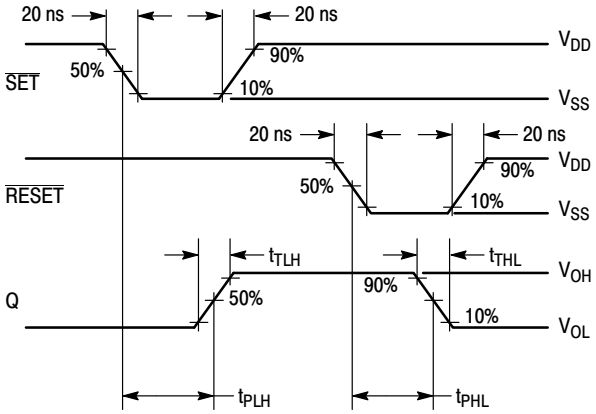
5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

AC WAVEFORMS

MC14043B



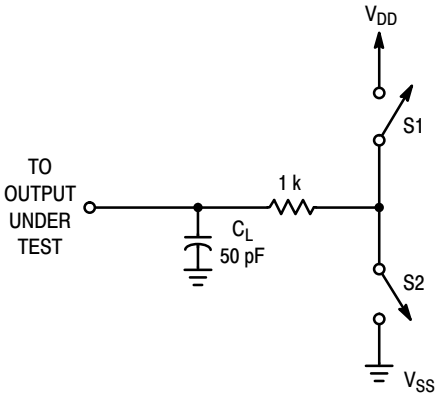
MC14044B

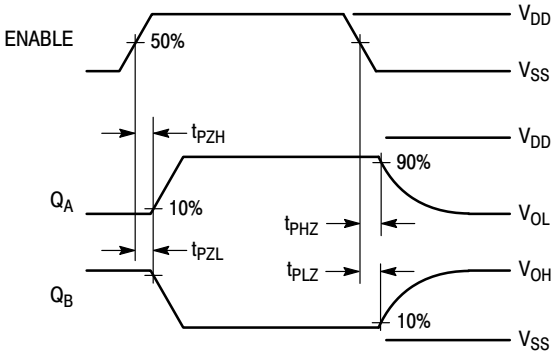


THREE−STATE ENABLE/DISABLE DELAYS

Set, Reset, Enable, and Switch Conditions for 3−State Tests

Test	Enable	S1	S2	Q	MC14043B		MC14044B	
					S	R	$\overline{S}$	$\overline{R}$
t_{PZH}	⌐	Open	Closed	A	V_{DD}	V_{SS}	V_{SS}	V_{DD}
t_{PZL}	⌐	Closed	Open	B	V_{SS}	V_{DD}	V_{DD}	V_{SS}
t_{PHZ}	¬	Open	Closed	A	V_{DD}	V_{SS}	V_{SS}	V_{DD}
t_{PLZ}	¬	Closed	Open	B	V_{SS}	V_{DD}	V_{DD}	V_{SS}





ORDERING INFORMATION

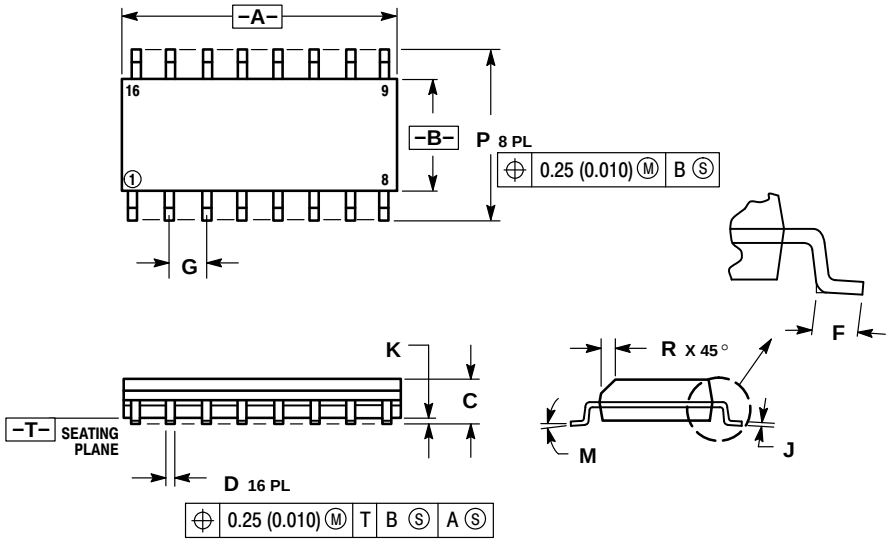
Device	Package	Shipping†
MC14043BDG	SOIC−16 (Pb−Free)	48 Units / Rail
NLV14043BDG*	SOIC−16 (Pb−Free)	48 Units / Rail
MC14043BDR2G	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel
NLV14043BDR2G*	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel
MC14043BFELG	SOEIAJ−16 (Pb−Free)	2000 Units / Tape & Reel
MC14044BDG	SOIC−16 (Pb−Free)	48 Units / Rail
NLV14044BDG*	SOIC−16 (Pb−Free)	48 Units / Rail
MC14044BDR2G	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel
NLV14044BDR2G*	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

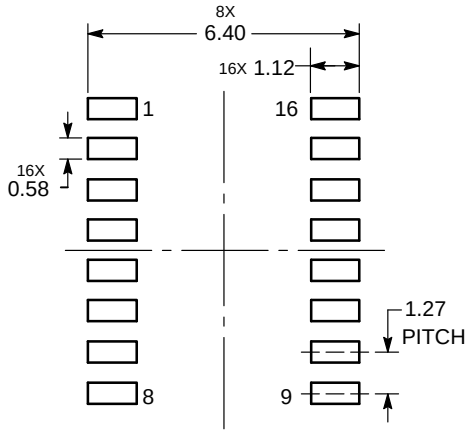
SOIC−16
D SUFFIX
CASE 751B−05
ISSUE K



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

SOLDERING FOOTPRINT*

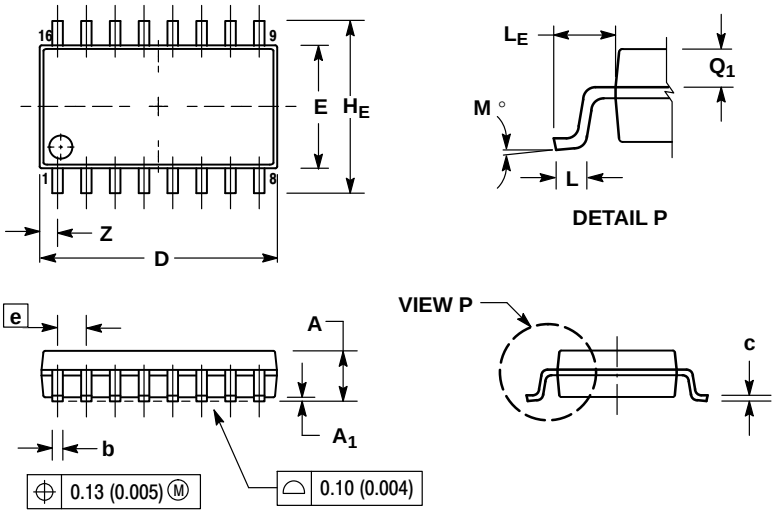


DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOEIAJ−16
F SUFFIX
CASE 966
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A_1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5817−1050

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

MC14043B/D

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Latches ***category:***

Click to view products by ON Semiconductor ***manufacturer:***

Other Similar products are found below :

ML4875CS-5 401639B 716165RB 74F373DW 74LVC373ADTR2G 74LVC573ADTR2G NL17SG373DFT2G NLV14044BDG 5962-8863901RA 5962-88639012A NLV14042BDR2G M22W-1333-21/3/45-90-02 (NI 2.L18.001-21 2.T18.001-21 2.T18.002-18 2.T18.006-18 CQ/AA-KEY CQ/A-M22X1,5-45-28 CQ/A-M22X1,5-45-32 M22-2-D5-2-21-01-P CY74FCT2373CTSOC 421283 MM74HC373WM MM74HC573WM 74LCX373MTC 74LVT16373MTDX 74VHC373MX KLD5.001-02 Z-0233-827-15 MIC58P01YV 74AHCT573D.112 74LCX16373MTDX CQ/A-M22X1,5-45-16 CQ/A-M22X1,5-45-18 CQ/A-M22X1,5-45-20 CQ/A-M22X1,5-45-24 CQ/A-M22X1,5-45-30 CQT/A-32-18 AE-V0 CQT/A-32 20-AE-V0 CQT/A-32 32-AE-V0 CY54FCT841ATDMB TPIC6B273DWRG4 Z-2106-25001-22 2.904.005 2.904.006 2.904.008 TC74HC573APF 74HC373DB.112 HEF4043BT.652 2.KLB-D5.001PA-07